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--21. An electro-optical device of an active matrix comprising:
a gate line provided on a substrate;
a data line provided on said substrate;
an exclusive wiring provided on said substrate;
a pixel electrode provided on said substrate and superposed on
said gate line with an insulator therebetween and superposed on said wiring
with an insulator therebetween; and
at least one transistor provided on said substrate and connected
with said gate line at a gate thereof and connected with said data line at one
of source and drain thereof and connected with said pixel electrode at the other
one of the source and drain.

22. An electro-optical device of an active matrix comprising:
a first gate line provided on a substrate;
a second gate line provided adjacent to said first gate line on said
substrate;
a first pixel electrode provided on said substrate and connected
with said first gate line through at least one first transistor; and
a second pixel electrode provided on said substrate and connected
with said second gate line through at least one second transistor,
wherein said first pixel electrode is superposed on said first gate
line with an insulator therebetween and is superposed on said second gate line
with another insulator therebetween.

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23. An electro-optical device of an active matrix comprising:
a gate line provided on a substrate;